

RoHS

Specification

SSC-SZ5M

(Rev.02_120103)

SSC		Customer
Drawn	Approval	Approval

SSC-SZ5M

January 2012

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SZ5M

Description

The Z-Power series is designed for high current operation and high flux output applications.

It incorporates state of the art SMD design and low thermal resistant material. The Z Power LED is ideal light sources for general illumination applications, custom designed solutions, automotive, large backlights and high performance torches.



SZ5M

Features

- Super high Flux output and high Luminance
- Designed for high current operation
- SMT solderable
- Lead Free product
- RoHS compliant

Applications

- Automotive interior / exterior lighting
- Automotive forward lighting
- General Torch
- Architectural lighting
- Projector light source
- Task lighting
- Decorative / Pathway lighting
- Remote / Solar powered lighting

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Full code of SZ5-M series

Full code form : X₁ X₂ X₃ – X₄ X₅ – X₆ X₇ – X₈ X₉

1. Part Number

- X₁ : Company
- X₂ : Z-Power LED series number
- X₃ : PKG series

2. Internal Number

- X₄: Series Code

P: P series

M: M series

X₅: Revision number

X₆ X₇ : Color specification

W0: Pure white

WN: Neutral white

WW: Warm white

X₈ X₉ : CRI Group

C8: CRI min.80

C9: CRI min.90

85: CRI min.85

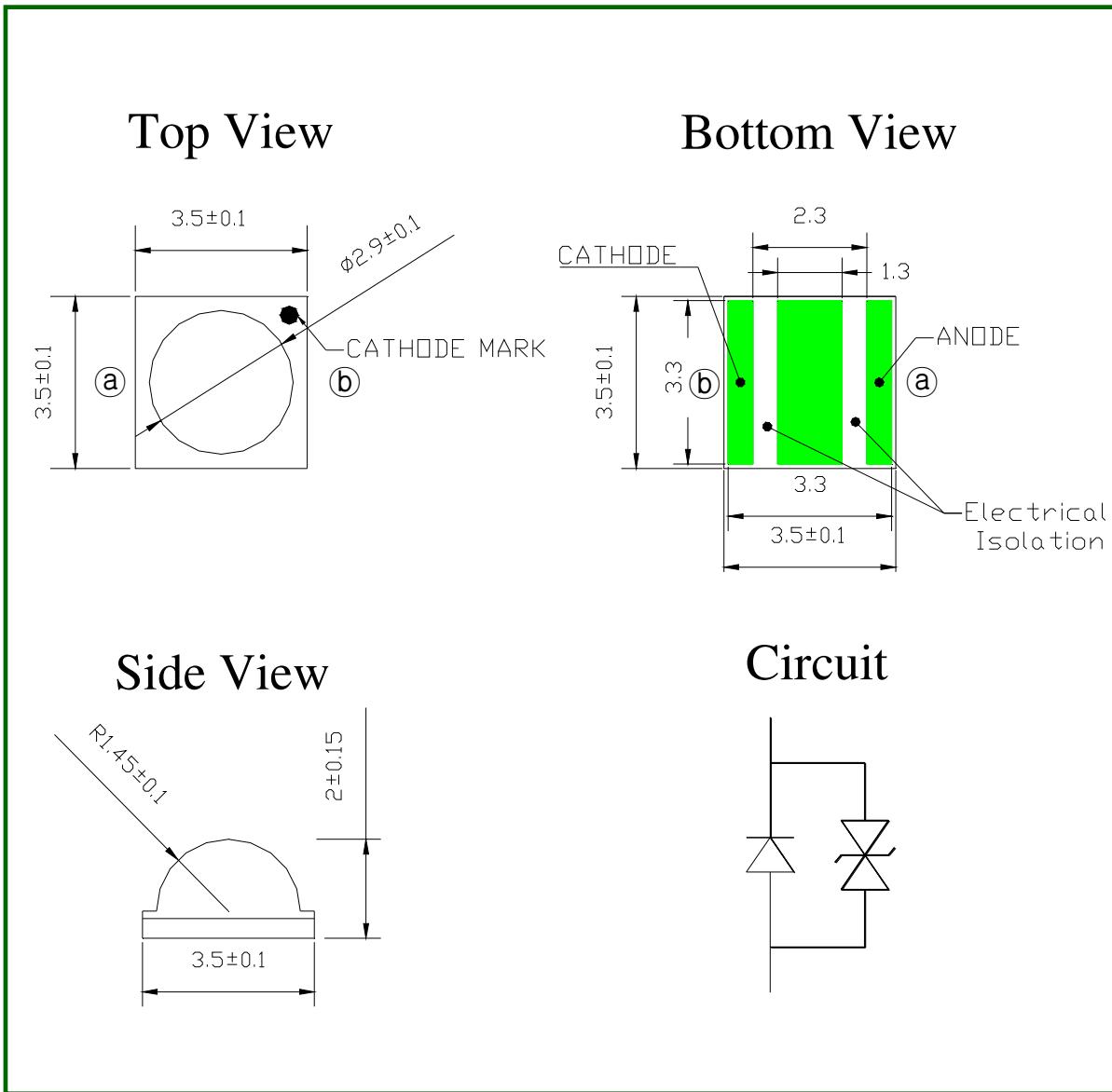
00: The others

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Outline dimensions



Notes :

- [1] All dimensions are in millimeters.
- [2] Scale : none
- [3] Undefined tolerance is ± 0.1 mm

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Characteristics of SZ5-M0-W0-00

Pure White

1-1 Electro-Optical characteristics at 350mA

(Ta=25°C, RH30%)

Parameter	Symbol	Value			Unit
		Min	Typ	Max	
Luminous Flux [1]	Φ_V [2]	-	125	-	lm
	$\Phi_V(T_j=100^\circ\text{C})$	-	115	-	
Correlated Color Temperature [3]	CCT	-	6000	-	K
CRI	R _a	-	70	-	-
Forward Voltage [4]	V _F	-	3.2	-	V
Thermal resistance (J to S)	R _{θJS}		5.8		K/W
View Angle	2θ 1/2		120		deg.

1-2 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	I _F	1200	mA
		1200(1/10duty@1kHz)	
Reverse Voltage	V _R	5	V
Power Dissipation	P _d	4	W
Junction Temperature	T _j	145(@ I _F ≤ 1200mA)	°C
Operating Temperature	T _{opr}	-40 ~ +85	°C
Storage Temperature	T _{stg}	-40 ~ +100	°C
ESD Sensitivity [5]	-	± 8,000V HBM	-

*Notes :

- [1] SSC maintains a tolerance of ±10% on flux and power measurements.
- [2] Φ_V is the total luminous flux output as measured with an integrating sphere.
- [3] Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.
Color coordinate : 0.005, CCT ±5% tolerance.
- [4] Tolerance is ±0.06V on forward voltage measurements
- [5] A zener diode is included to protect the product from ESD.

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Characteristics of SZ5-M0-W0-C8

Pure White

1-1 Electro-Optical characteristics at 350mA

(Ta=25°C, RH30%)

Parameter	Symbol	Value			Unit
		Min	Typ	Max	
Luminous Flux [1]	Φ_V [2]	-	115	-	lm
	$\Phi_V(T_j=100^\circ\text{C})$	-	105	-	
Correlated Color Temperature [3]	CCT	-	6000	-	K
CRI	R _a	80	-	-	-
Forward Voltage [4]	V _F	-	3.2	-	V
Thermal resistance (J to S)	R _{θJS}		5.8		K/W
View Angle	2θ 1/2	120			deg.

1-2 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	I _F	1200	mA
		1200(1/10duty@1kHz)	
Reverse Voltage	V _R	5	V
Power Dissipation	P _d	4	W
Junction Temperature	T _j	145(@ I _F ≤ 1200mA)	°C
Operating Temperature	T _{opr}	-40 ~ +85	°C
Storage Temperature	T _{stg}	-40 ~ +100	°C
ESD Sensitivity [5]	-	± 8,000V HBM	-

*Notes :

- [1] SSC maintains a tolerance of ±10% on flux and power measurements.
- [2] Φ_V is the total luminous flux output as measured with an integrating sphere.
- [3] Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.
Color coordinate : 0.005, CCT ±5% tolerance.
- [4] Tolerance is ±0.06V on forward voltage measurements
- [5] A zener diode is included to protect the product from ESD.

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Characteristics of SZ5-M0-WN-C8

Neutral White

1-1 Electro-Optical characteristics at 350mA

(Ta=25°C, RH30%)

Parameter	Symbol	Value			Unit
		Min	Typ	Max	
Luminous Flux [1]	Φ_V [2]	-	108	-	lm
	$\Phi_V(T_j=100^\circ\text{C})$	-	98	-	
Correlated Color Temperature [3]	CCT	-	4000	-	K
CRI	R _a	80		-	-
Forward Voltage [4]	V _F	-	3.2	-	V
Thermal resistance (J to S)	R _{θJS}		5.8		K/W
View Angle	2θ ½	120			deg.

1-2 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	I _F	1200	mA
		1200(1/10duty@1kHz)	
Reverse Voltage	V _R	5	V
Power Dissipation	P _d	4	W
Junction Temperature	T _j	145(@ I _F ≤ 1200mA)	°C
Operating Temperature	T _{opr}	-40 ~ +85	°C
Storage Temperature	T _{stg}	-40 ~ +100	°C
ESD Sensitivity [5]	-	± 8,000V HBM	-

*Notes :

- [1] SSC maintains a tolerance of ±10% on flux and power measurements.
- [2] Φ_V is the total luminous flux output as measured with an integrating sphere.
- [3] Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.
Color coordinate : 0.005, CCT ±5% tolerance.
- [4] Tolerance is ±0.06V on forward voltage measurements
- [5] A zener diode is included to protect the product from ESD.

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Characteristics of SZ5-M0-WN-00

Neutral White

1-1 Electro-Optical characteristics at 350mA

(Ta=25°C, RH30%)

Parameter	Symbol	Value			Unit
		Min	Typ	Max	
Luminous Flux [1]	Φ_V [2]	-	118	-	lm
	$\Phi_V(T_j=100^\circ\text{C})$	-	107	-	
Correlated Color Temperature [3]	CCT	-	4000	-	K
CRI	R _a	-	67	-	-
Forward Voltage [4]	V _F	-	3.2	-	V
Thermal resistance (J to S)	R _{θJS}		5.8		K/W
View Angle	2θ 1/2		120		deg.

1-2 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	I _F	1200	mA
		1200(1/10duty@1kHz)	
Reverse Voltage	V _R	5	V
Power Dissipation	P _d	4	W
Junction Temperature	T _j	145(@ I _F ≤ 1200mA)	°C
Operating Temperature	T _{opr}	-40 ~ +85	°C
Storage Temperature	T _{stg}	-40 ~ +100	°C
ESD Sensitivity [5]	-	± 8,000V HBM	-

*Notes :

- [1] SSC maintains a tolerance of ±10% on flux and power measurements.
- [2] Φ_V is the total luminous flux output as measured with an integrating sphere.
- [3] Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.
Color coordinate : 0.005, CCT ±5% tolerance.
- [4] Tolerance is ±0.06V on forward voltage measurements
- [5] A zener diode is included to protect the product from ESD.

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Characteristics of SZ5-M0-WW-C8

Warm white

1-1 Electro-Optical characteristics at 350mA

Parameter	Symbol	Value			Unit
		Min	Typ	Max	
Luminous Flux ^[1]	Φ_V ^[2]	-	100	-	lm
	$\Phi_V(T_j=100^\circ\text{C})$	-	91	-	
Correlated Color Temperature ^[3]	CCT	-	3000	-	K
CRI	R _a	80	-	-	-
Forward Voltage ^[4]	V _F	-	3.2	-	V
Thermal resistance (J to S)	R _{θJS}		5.8		K/W
View Angle	2θ ½	120			deg.

1-2 Absolute Maximum Ratings

Parameter		Value	Unit
Forward Current	I _F	1200	mA
		1200(1/10duty@1kHz)	
Reverse Voltage	V _R	5	V
Power Dissipation	P _d	4	W
Junction Temperature	T _j	145(@ I _F ≤ 1200mA)	°C
Operating Temperature	T _{opr}	-40 ~ +85	°C
Storage Temperature	T _{stg}	-40 ~ +100	°C
ESD Sensitivity ^[5]	-	± 8,000V HBM	-

*Notes :

[1] SSC maintains a tolerance of ±10% on flux and power measurements.

[2] Φ_V is the total luminous flux output as measured with an integrating sphere.

[3] Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.

Color coordinate : 0.005, CCT ±5% tolerance.

[4] Tolerance is ±0.06V on forward voltage measurements

[5] A zener diode is included to protect the product from ESD.

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Characteristics of SZ5-M0-WW-85

Warm white

1-1 Electro-Optical characteristics at 350mA

Parameter	Symbol	Value			Unit
		Min	Typ	Max	
Luminous Flux ^[1]	Φ_V ^[2]	-	96	-	lm
	$\Phi_V(T_j=100^\circ\text{C})$	-	87	-	
Correlated Color Temperature ^[3]	CCT	-	3000	-	K
CRI	R _a	85	-	-	-
Forward Voltage ^[4]	V _F	-	3.2	-	V
Thermal resistance (J to S)	R _{θJS}		5.8		K/W
View Angle	2θ ½	120			deg.

1-2 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	I _F	1200	mA
		1200(1/10duty@1kHz)	
Reverse Voltage	V _R	5	V
Power Dissipation	P _d	4	W
Junction Temperature	T _j	145(@ I _F ≤ 1200mA)	°C
Operating Temperature	T _{opr}	-40 ~ +85	°C
Storage Temperature	T _{stg}	-40 ~ +100	°C
ESD Sensitivity ^[5]	-	± 8,000V HBM	-

*Notes :

- [1] SSC maintains a tolerance of ±10% on flux and power measurements.
- [2] Φ_V is the total luminous flux output as measured with an integrating sphere.
- [3] Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.
Color coordinate : 0.005, CCT ±5% tolerance.
- [4] Tolerance is ±0.06V on forward voltage measurements
- [5] A zener diode is included to protect the product from ESD.

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Characteristics of SZ5-M0-WW-C9

Warm white

1-1 Electro-Optical characteristics at 350mA

Parameter	Symbol	Value			Unit
		Min	Typ	Max	
Luminous Flux ^[1]	Φ_V ^[2]	-	87	-	lm
	$\Phi_V(T_j=100^\circ\text{C})$	-	79	-	
Correlated Color Temperature ^[3]	CCT	-	3000	-	K
CRI	R _a	90	-	-	-
Forward Voltage ^[4]	V _F	-	3.2	-	V
Thermal resistance (J to S)	R _{θJS}		5.8		K/W
View Angle	2θ ½		120		deg.

1-2 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	I _F	1200	mA
		1200(1/10duty@1kHz)	
Reverse Voltage	V _R	5	V
Power Dissipation	P _d	4	W
Junction Temperature	T _j	145(@ I _F ≤ 1200mA)	°C
Operating Temperature	T _{opr}	-40 ~ +85	°C
Storage Temperature	T _{stg}	-40 ~ +100	°C
ESD Sensitivity ^[5]	-	± 8,000V HBM	-

*Notes :

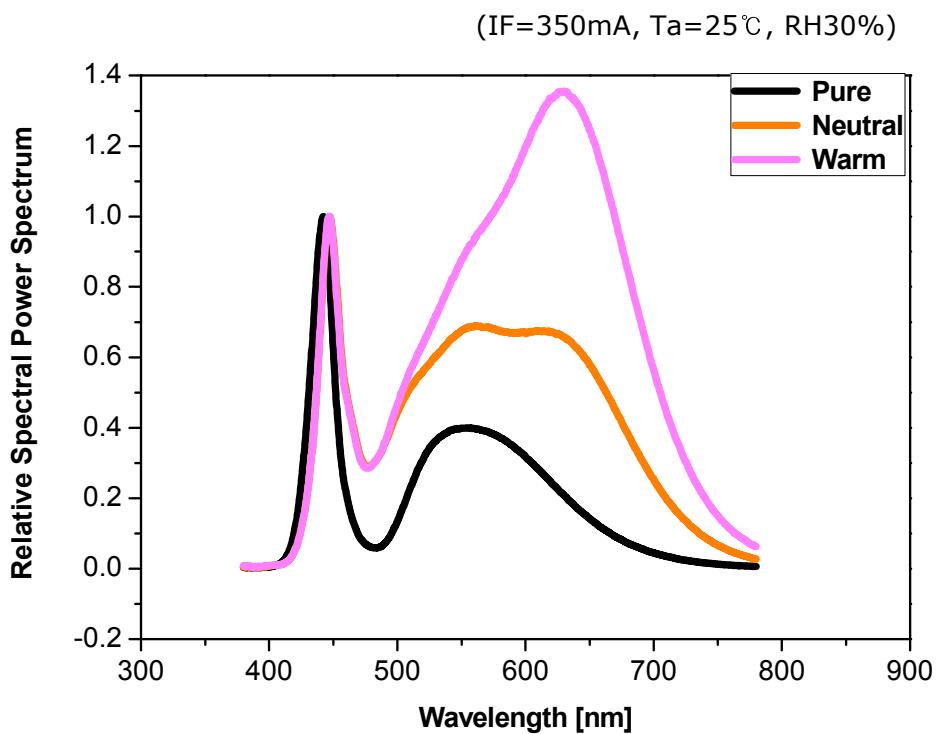
- [1] SSC maintains a tolerance of ±10% on flux and power measurements.
- [2] Φ_V is the total luminous flux output as measured with an integrating sphere.
- [3] Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.
Color coordinate : 0.005, CCT ±5% tolerance.
- [4] Tolerance is ±0.06V on forward voltage measurements
- [5] A zener diode is included to protect the product from ESD.

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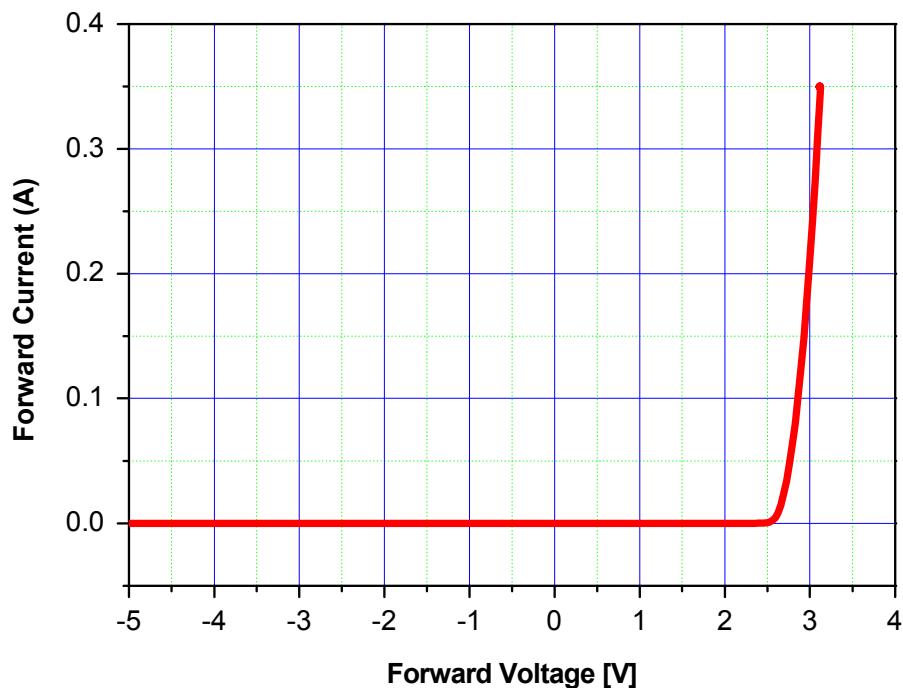
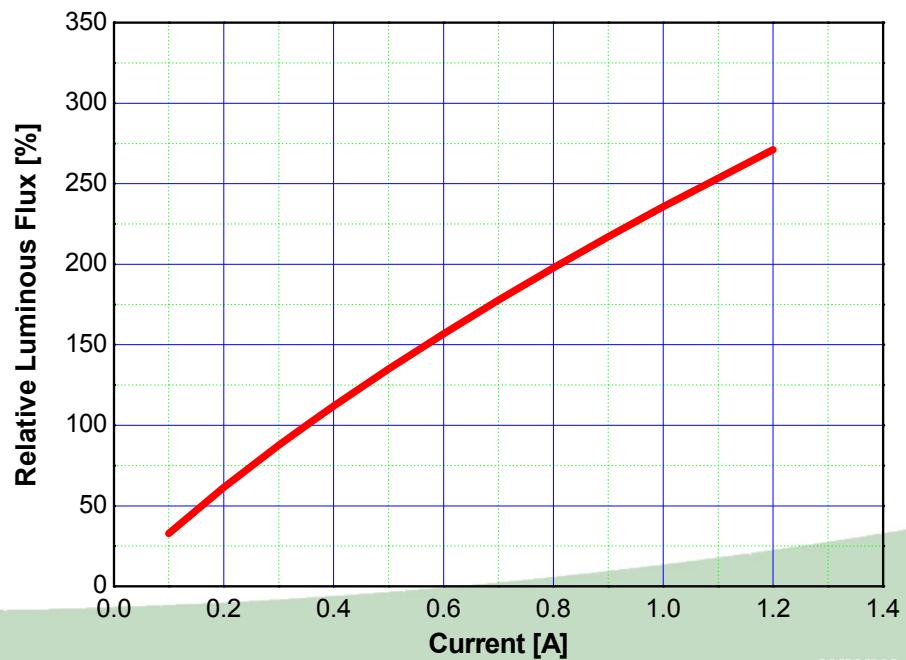
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Color Spectrum



Forward Current Characteristics

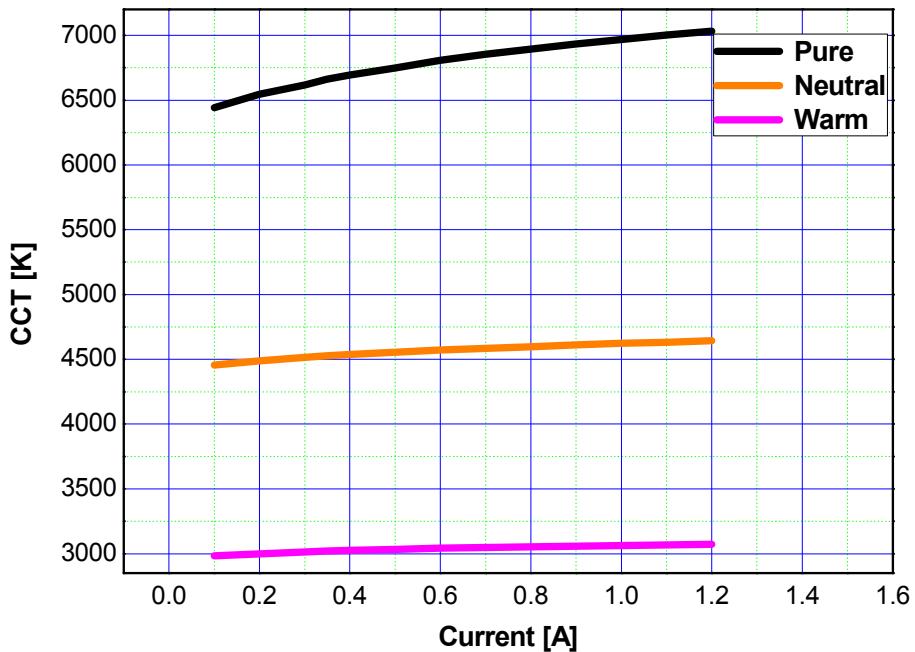
Forward Voltage vs. Forward Current, Ta=25°C**Forward Current vs. Normalized Relative Luminous Flux, Ta=25°C..**

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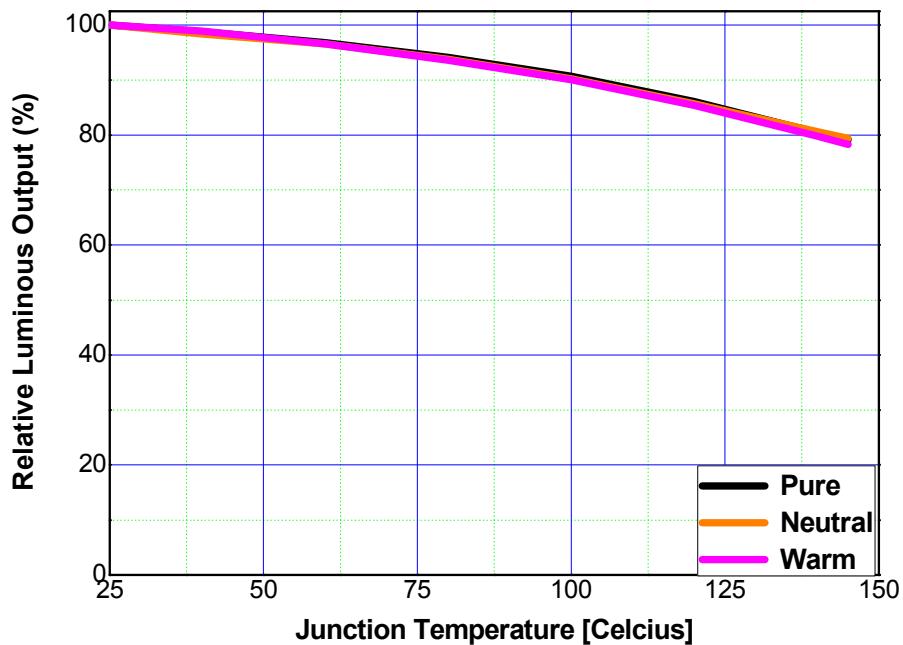
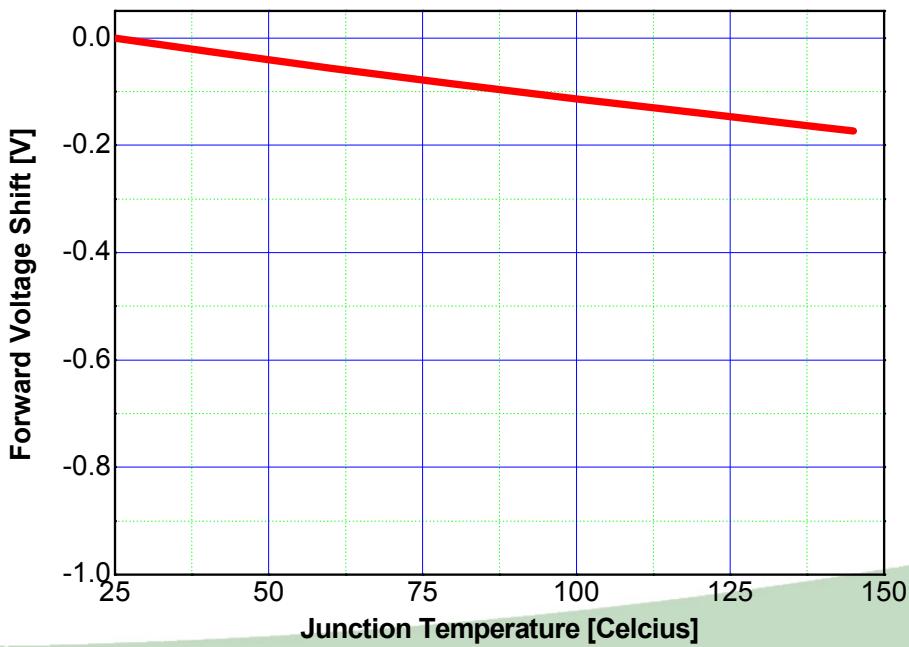
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CCT vs. Forward Current, Ta=25°C



Junction Temperature Characteristics

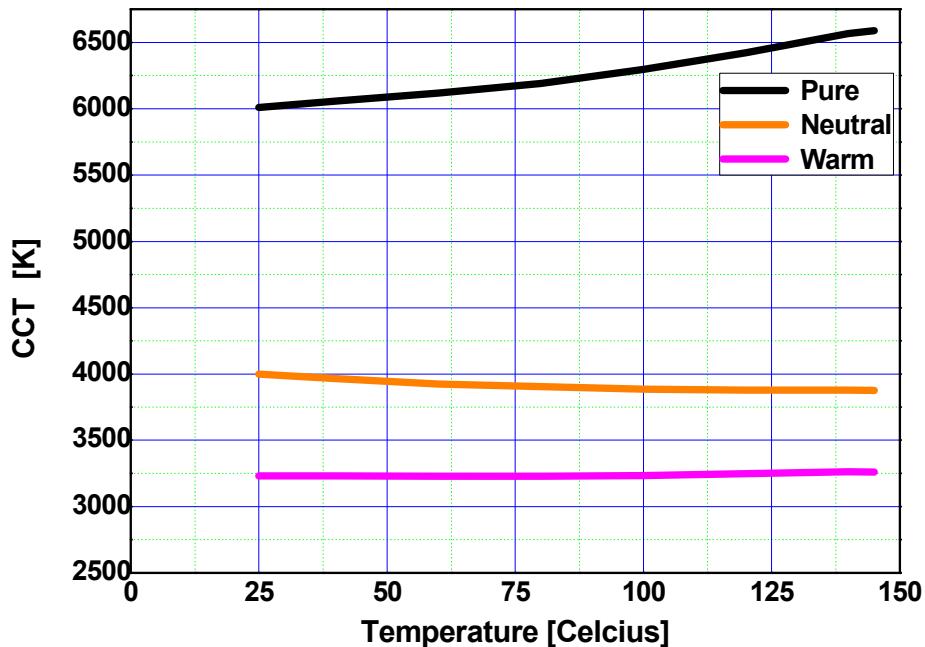
Relative Light Output vs. Junction Temperature at IF=350mA**VF vs. Junction Temperature at IF=350mA**

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CCT vs. Junction Temperature at IF=350mA

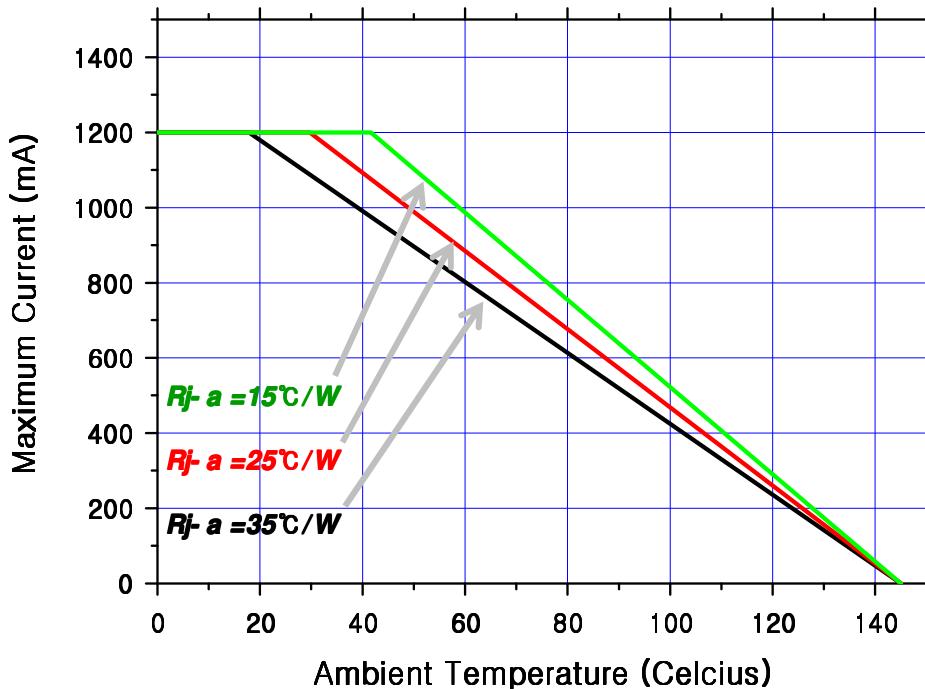


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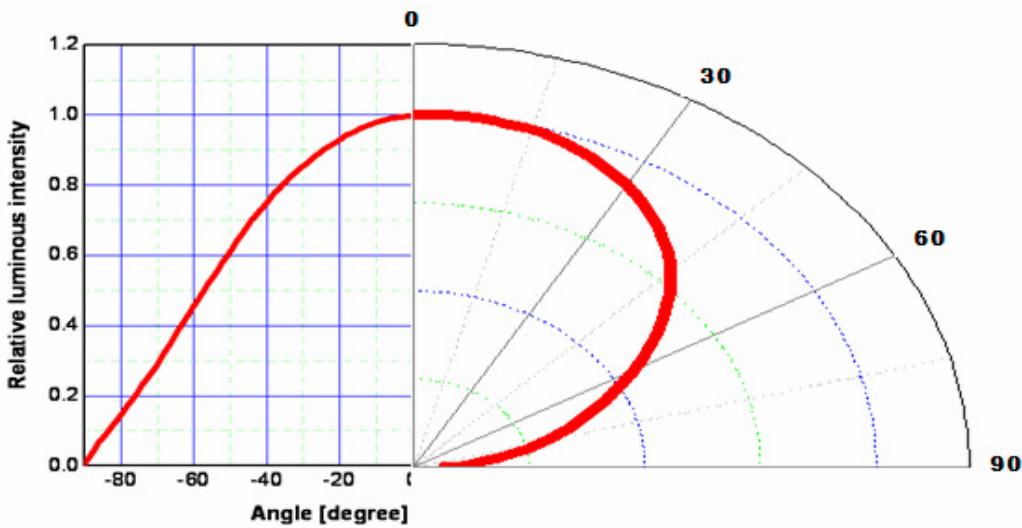
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Ambient Temperature vs. Allowable Forward Current
Pure White, Neutral White, Warm White ($T_{jmax} = 145^\circ\text{C}$, @1.2A)

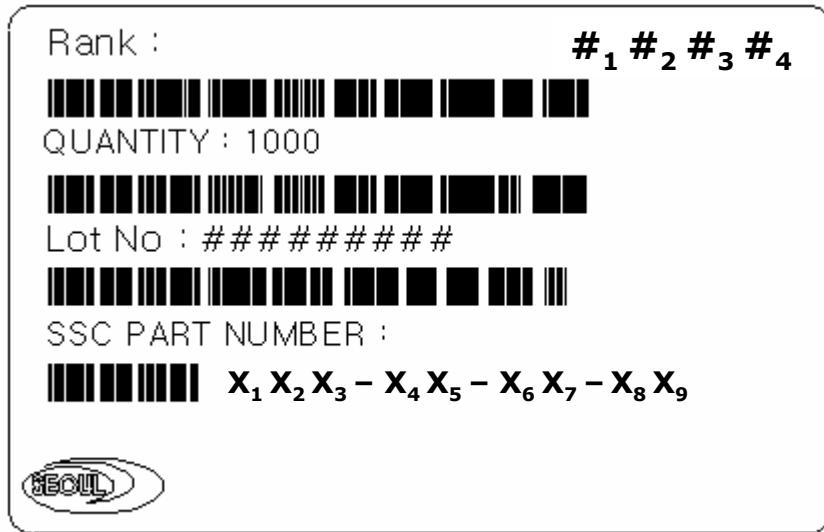


Radiation pattern at 350mA



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Label



Full code form :

X₁ X₂ X₃ – X₄ X₅ – X₆ X₇ – X₈ X₉

- X₁X₂X₃ : **Part Number**
- X₄: **Series Code**
- X₅: **Revision number**
- X₆X₇ : **Color specification**
- X₈X₉ : **CRI group**

Rank

#₁#₂#₃#₄

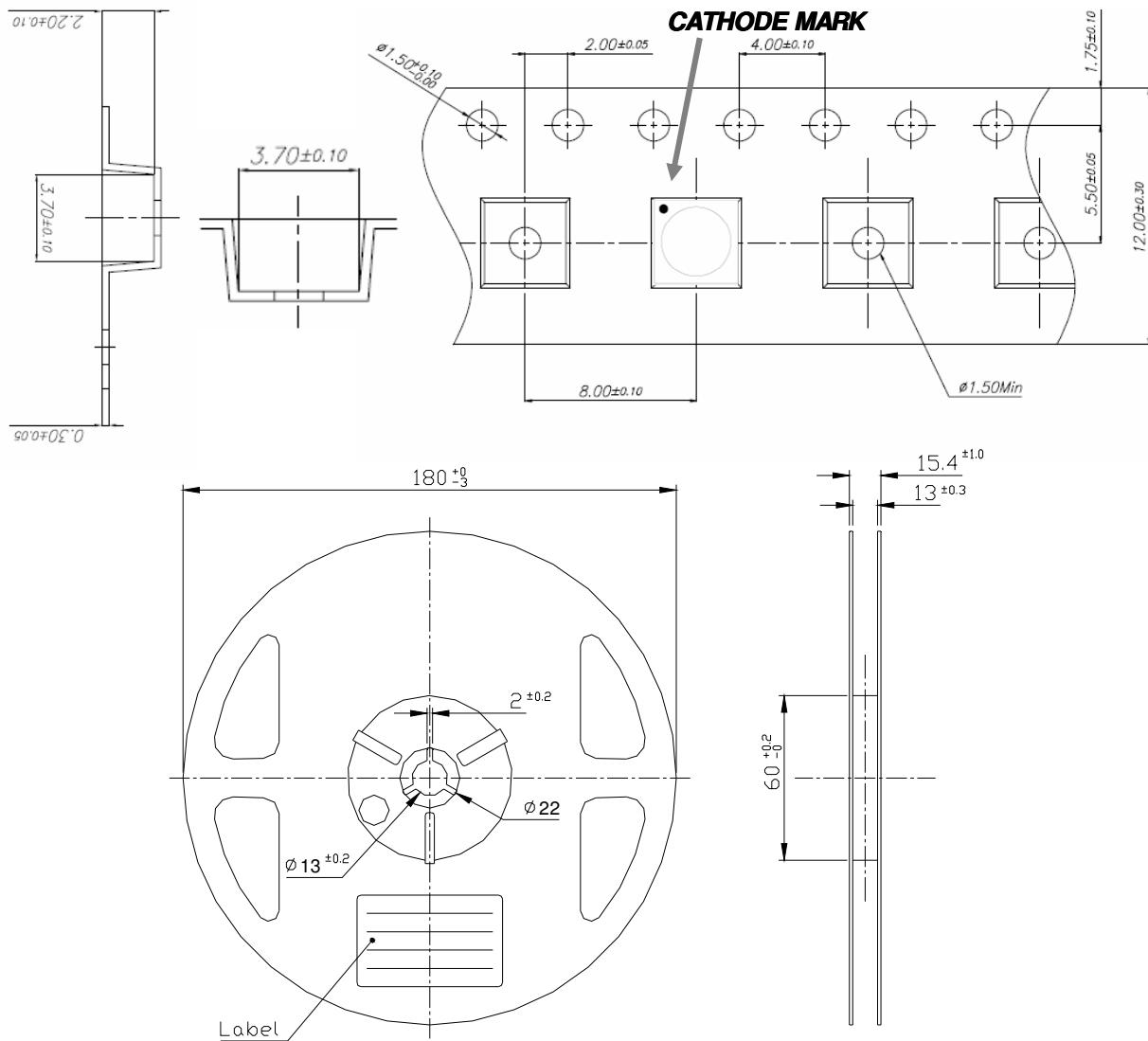
- #₁ : **Luminous Flux : LF [lm]**
- #₂#₃ : **Color coordinates : x, y**
- #₄ : **Forward Voltage : V_F [V]**

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Emitter Carrier & Reel Packaging



NOTES:

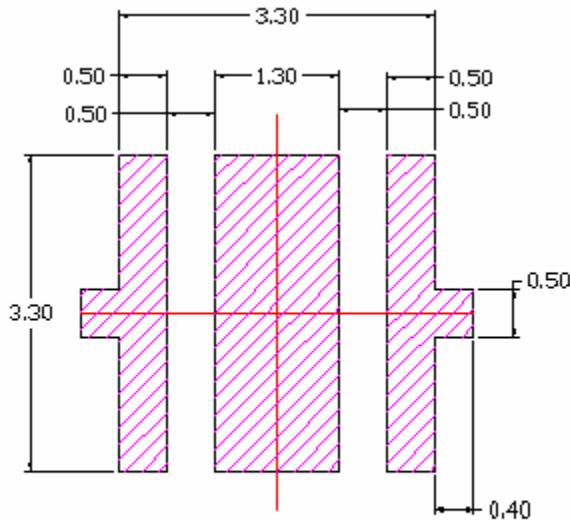
1. 10 sprocket hole pitch cumulative tolerance ± 0.20
2. Camber not to exceed 1mm in 250mm
3. Material: Black conductive Polystyrene
4. Ao and Bo measured on a plane 0.3mm above the bottom of the pocket
5. Ko measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
6. Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole.
7. Pocket center and pocket hole center must be same position.

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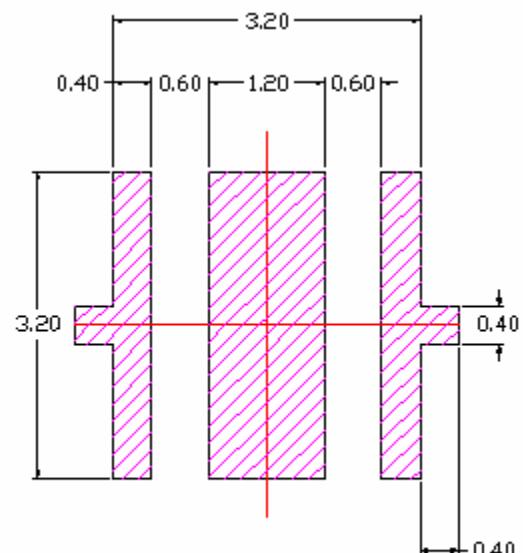
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Recommended solder pad



Recommended PCB Solder Pad



Recommended Stencil Pattern

Notes :

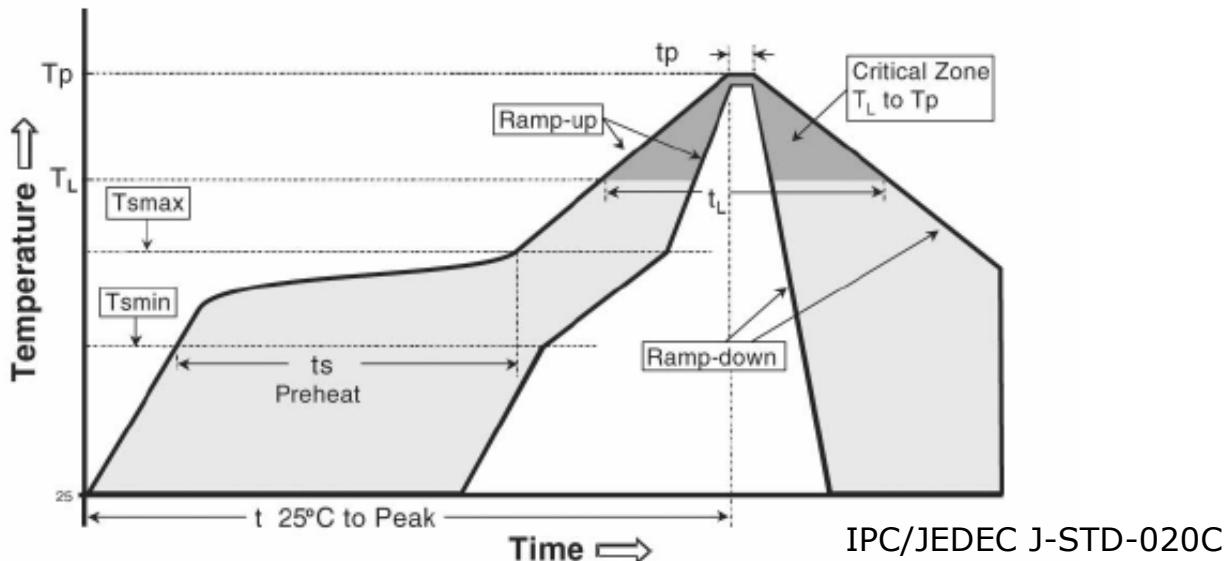
- [1] All dimensions are in millimeters.
- [2] Scale : none
- [3] This drawing without tolerances are for reference only

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Reflow Soldering Conditions / Profile



Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate (Tsmax to Tp)	3 °C/second max.	3 °C/second max.
Preheat - Temperature Min (Tsmin) - Temperature Max (Tsmax) - Time (Tsmin to Tsmax) (ts)	100 °C 150 °C 60-120 seconds	150 °C 200 °C 60-180 seconds
Time maintained above: - Temperature (TL) - Time (tL)	183 °C 60-150 seconds	217 °C 60-150 seconds
Peak Temperature (Tp)	215°C	260°C
Time within 5°C of actual Peak Temperature (tp) ²	10-30 seconds	20-40 seconds
Ramp-down Rate	6 °C/second max.	6 °C/second max.
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

* **Caution**

1. Reflow soldering should not be done more than one time.
2. Repairs should not be done after the LEDs have been soldered. When repair is unavoidable, suitable tools must be used.
3. Die slug is to be soldered.
4. When soldering, do not put stress on the LEDs during heating.
5. After soldering, do not warp the circuit board.
6. Recommend to use a convection type reflow machine with 7 ~ 8 zones.

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Precaution for use

- Storage

To avoid the moisture penetration, we recommend storing Z Power LEDs in a dry box with a desiccant. The recommended storage temperature range is 5C to 30C and a maximum humidity of 50%.

- Use Precaution after Opening the Packaging

Use proper SMD techniques when the LED is to be soldered dipped as separation of the lens may affect the light output efficiency.

Pay attention to the following:

- Soldering should be done immediately after opening the package (within 24Hrs).
 - Required conditions after opening the package
 - Sealing
 - Temperature : 5 ~ 40°C Humidity : less than 30%
 - If the package has been opened more than 4 week or the color of the desiccant changes, components should be dried for 10-12hr at 60±5°C
- Do not apply mechanical force or excess vibration during the cooling process to normal temperature after soldering.
 - Do not rapidly cool device after soldering.
 - Components should not be mounted on warped (non coplanar) portion of PCB.
 - Radioactive exposure is not considered for the products listed here in.
 - Gallium arsenide is used in some of the products listed in this publication. These products are dangerous if they are burned or shredded in the process of disposal. It is also dangerous to drink the liquid or inhale the gas generated by such products when chemically disposed of.
 - This device should not be used in any type of fluid such as water, oil, organic solvent and etc. When washing is required, IPA (Isopropyl Alcohol) should be used.
 - When the LEDs are in operation the maximum current should be decided after measuring the package temperature.
 - LEDs must be stored properly to maintain the device. If the LEDs are stored for 3 months or more after being shipped from SSC, a sealed container with a nitrogen atmosphere should be used for storage.
 - The appearance and specifications of the product may be modified for improvement without notice.
 - Long time exposure of sunlight or occasional UV exposure will cause lens discoloration.
 - The slug is isolated from anode electrically. Therefore, we recommend that you don't isolate the heat sink.
 - Attaching LEDs, do not use adhesives that outgas organic vapor.

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Handling of Silicone resin LEDs

The Z-Power LED is encapsulated with a silicone resin for the highest flux efficiency.

Notes for handling:

- Avoid touching silicone resin parts especially with sharp tools such as Pincetter (Tweezers)
- Avoid leaving fingerprints on silicone resin parts.
- Silicone resin will attract dust so use covered containers for storage.
- When populating boards in SMT production, there are basically no restrictions regarding the form of the pick and place nozzle, except that excessive mechanical pressure on the surface of the resin must be prevented.
- It is not recommend to cover the silicone resin of the LEDs with other resin (epoxy, urethane, etc)



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помошь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помошь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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